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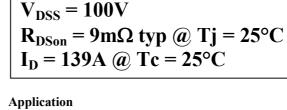


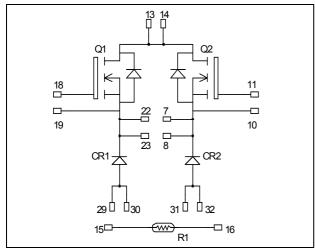






Dual Buck chopper MOSFET Power Module





All multiple inputs and outputs must be shorted together Example: 13/14; 29/30; 22/23 ...

- AC and DC motor control
- Switched Mode Power Supplies

Features

- Power MOS V® MOSFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
- Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- Each leg can be easily paralleled to achieve a single buck of twice the current capability
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage	100	V	
т	Continue Desir Connect	$T_c = 25^{\circ}C$	139	
I_D	Continuous Drain Current	$T_c = 80$ °C	100 *	Α
I_{DM}	Pulsed Drain current	430		
V_{GS}	Gate - Source Voltage	±30	V	
R _{DSon}	Drain - Source ON Resistance	10	mΩ	
P_D	Maximum Power Dissipation	390	W	
I_{AR}	Avalanche current (repetitive and non repetitive)	100	A	
E_{AR}	Repetitive Avalanche Energy	50	T	
E_{AS}	Single Pulse Avalanche Energy	3000	mJ	

^{*} Specification of MOSFET device but output current must be limited to 75A to not exceed a delta of temperature greater than 30°C for the connectors.

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
T	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 100V$	$T_j = 25^{\circ}C$			100	μА
$I_{ m DSS}$		$V_{GS} = 0V, V_{DS} = 80V$	$T_j = 125$ °C			500	
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 69.5A$			9	10	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 2.5 \text{mA}$		2		4	V
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$				±100	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V$		9875		
C_{oss}	Output Capacitance	$V_{DS} = 25V$		3940		pF
C_{rss}	Reverse Transfer Capacitance	f=1MHz		1470		
Q_{g}	Total gate Charge	$V_{GS} = 10V$		350		
Q_{gs}	Gate – Source Charge	$V_{\rm Bus} = 50V$		60		nC
$Q_{gd} \\$	Gate – Drain Charge	$I_{D} = 139A$		180		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C		35		
$T_{\rm r}$	Rise Time	$V_{GS} = 15V$		70		nc
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 66V$ $I_D = 139A$ $R_G = 5\Omega$		95		ns
T_{f}	Fall Time			125		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C $V_{GS} = 15V$, $V_{Bus} = 66V$ $I_D = 139A$, $R_G = 5\Omega$		552		1
E_{off}	Turn-off Switching Energy			604		μJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C $V_{GS} = 15V$, $V_{Bus} = 66V$ $I_D = 139A$, $R_G = 5\Omega$		608		1
E_{off}	Turn-off Switching Energy			641		μJ

Diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			200			V
I_{RM}	Maximum Reverse Leakage Current	V -200V	$T_j = 25^{\circ}C$			250	۸
1 _{RM}		$V_R=200V$	$T_j = 125$ °C			500	μΑ
I_F	DC Forward Current		Tc = 80°C		100		A
	Diode Forward Voltage	$I_F = 100A$			1		
V_{F}		$I_F = 200A$			1.4		V
		$I_{\rm F} = 100 A$	$T_i = 125$ °C		0.9		
t_{rr}	Reverse Recovery Time	$I_F = 100A$ $V_R = 133V$	$T_j = 25^{\circ}C$		60		ns
чr			$T_{j} = 125^{\circ}C$		110		113
Q_{rr}	Reverse Recovery Charge	$di/dt = 200 A/\mu s$ $T_j = 25^{\circ}C$	$T_j = 25$ °C		200		nC
			$T_{j} = 125^{\circ}C$		840		iiC

2 - 7



Thermal and package characteristics

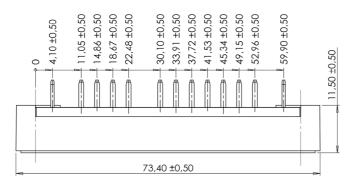
Symbol	Characteristic			Min	Тур	Max	Unit
D	Junction to Case Thermal Resistance		Transistor			0.32	°C/W
R_{thJC}			Diode			0.55	C/ W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		150	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature					100	
Torque	Mounting torque	To heatsink	M4	2	•	3	N.m
Wt	Package Weight				•	110	g

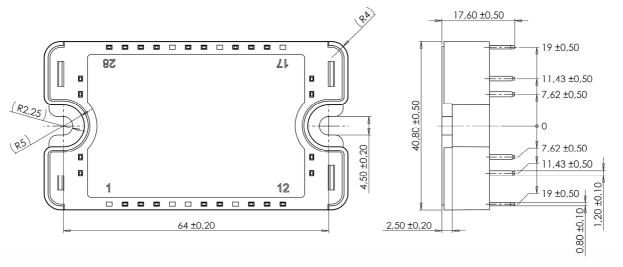
Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic	Min	Typ	Max	Unit
R ₂₅	Resistance @ 25°C		50		kΩ
B 25/85	$T_{25} = 298.15 \text{ K}$		3952		K

$$R_T = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature} \\ R_T: \text{ Thermistor value at T}$$

SP3 Package outline (dimensions in mm)

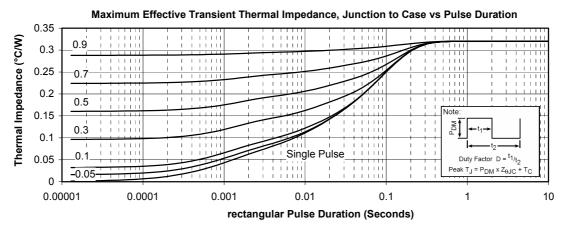


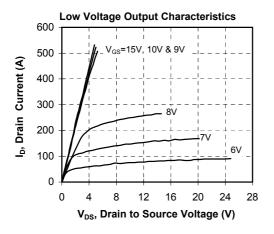


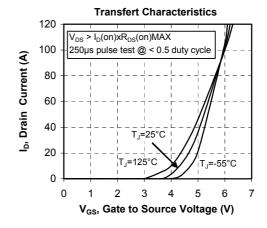
See application note 1901 - Mounting Instructions for SP3 Power Modules on www.microsemi.com

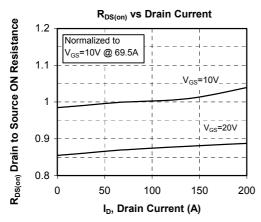


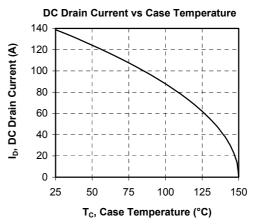
Typical Performance Curve



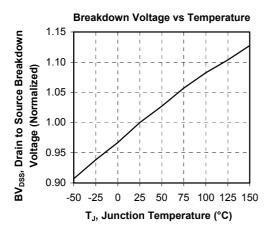


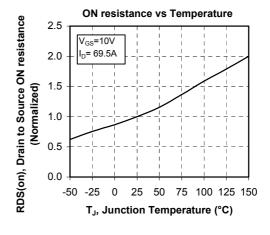


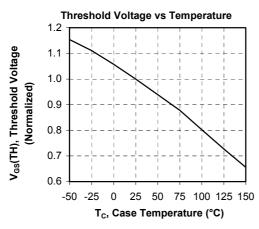


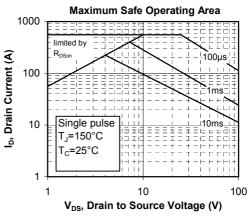


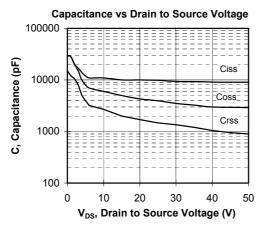


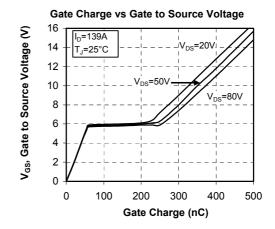




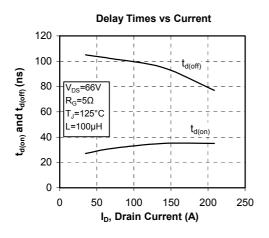


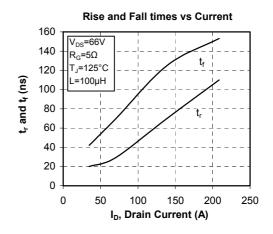


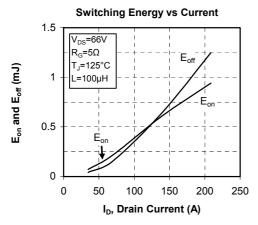


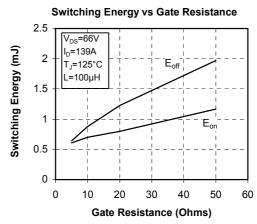


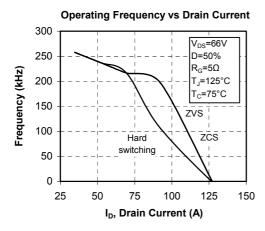


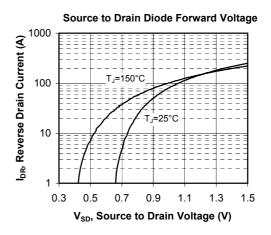












6 - 7

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